IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

re application of: Chien-Chao Huang et al.

Examiner: Unknown

Serial No.: 10/627,849

Confirmation No.: 2641

Filed:

July 25, 2003

Attorney Docket No.: N1085-00151

For:

SEMICONDUCTOR DEVICE WITH MODIFIED CHANNEL COMPRESSIVE

STRESS AND THE METHOD FOR MAKING SAME

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

This Information Disclosure Statement is being filed in connection with the patent application referenced above. The Examiner is requested to consider each of the references cited herein and forward an initialed copy of the enclosed PTO Form 1449 to the undersigned representative. This Statement is being filed:

	□ .	Upon	filing the application.							
contin	Within three months from the filing date of this application, which is not a tinued prosecution application.									
		Within	Vithin three months from date of entry of the national stage for this application.							
	\boxtimes	Before	e the mailing date of a first Office action on the merits for this application.							
contin	□ ued exa		Before the mailing date of a first Office action after the filing of a request for ination.							
	Before the mailing date of any of: (i) a Final Office Action, (ii) a Notice of llowance, and (iii) any other action that closes prosecution of this application. The Statement accompanied by:									
			A Statement pursuant to 37 C.F.R. §1.97(e) or							
			The fee set forth in 37 C.F.R. §1.17(p), believed to be							
			Before payment of the Issue Fee. The Statement is accompanied by:							
			A Statement pursuant to 37 C.F.R. §1.97(e) and							
			The fee set forth in 37 C.F.R. §1.17(p), believed to be							

1.	Provision of Copies				
enclos	A copy of each of the references listed on the attached Form PTO Form 1449 is ed herewith and forms a part hereof.				
part he	A translation of References AA, AB and AC are enclosed herewith and form a ereof.				
applica	A copy of the European Search Report from a corresponding or related EPO ation is enclosed herewith.				
applica	A copy of the International Search Report from a corresponding or related PCT ation is enclosed herewith.				
Applic submit	This application claims priority, pursuant to 35 U.S.C. §120, to prior U.S. cation No, filed References not submitted herewith were tted to or cited by the Office in the prior application(s).				
II.	Fee				
No fee is believed due in connection with filing of this Statement. However, in the event a fee or refund is due, the Commissioner is authorized to charge any fee associated with this communication or credit any overpayment to Deposit Account No. 04-1679 (N1085-00151).					
Statem	The fee in the amount \$ that is due in connection of filing of this nent was paid upon electronic filing of a corresponding Statement, which was made on using the ePAVE software.				
to be d	The fee set forth in 37 C.F.R. §1.17(p), believed to be \$, is believed lue in connection of filing of this Statement.				
	A check in the amount \$ is enclosed.				
comm	The Commissioner is authorized to charge any other fee associated with this unication, or credit any overpayment, to Deposit Account No. 04-1679 (N1085-00151).				
	Respectfully submitted,				
Dated:	1 1004 Edward J. Lynch, Reg. No. 24,422				

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List of Paten Cited by App (Use several	plicant		Applicant Chien-Chao Huang et al.							
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U. S. PATEN	T DOCU	MENTS								
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	1	Ootsuka, F., et al., "A Highly Dense, High-Performance 130nm node CMOS Technology for Large Scale System-on-a-Chip Applications", IDEM 00, IEEE 0-7803-6438, (APR 2000), pp. 575-578								
	2	Tiwari, S., et al. "Hole Mobility Improvement in Silicon-on-Insulator and Bulk Silicon Transistors Using Local Strain", IDEM 97, (APR 2000), pp. 939-941								

EXAMINER	DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.